## NSN 5961-00-493-0789

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-493-0789 **Inclosure Material:** Metal **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 10.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 40.0 static forward current transfer ratio, common-emitter all transistor **Special Features:** All transistor junction pattern arrangement: npn Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0